

# ST2001FX HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

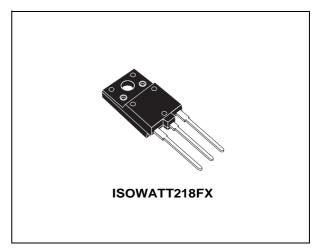
- NEW SERIES, ENHANCED PERFORMANCE
- FULLY INSULATED PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING
- HIGH VOLTAGE CAPABILITY
- HIGH SWITCHING SPEED
- TIGTHER hfe CONTROL
- IMPROVED RUGGEDNESS

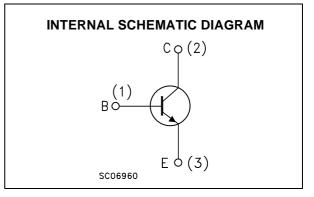
#### **APPLICATIONS:**

 HORIZONTAL DEFLECTION FOR COLOR TVS OVER 21 INCHES AND 15 INCHES MONITORS

#### DESCRIPTION

The device is manufactured using Diffused Collector technology for more stable operation Vs base drive circuit variations resulting in very low worst case dissipation.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit	
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	1500	V	
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)	600	V	
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	7	V	
Ι <sub>C</sub>	Collector Current	10	A	
ICM	Collector Peak Current (t <sub>p</sub> < 5 ms)	20	A	
Ι <sub>Β</sub>	Base Current	7	A	
P <sub>tot</sub>	Total Dissipation at $T_c = 25 \text{ °C}$	63	W	
V <sub>ins</sub>	Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink	2500		
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C	
Tj	Max. Operating Junction Temperature	150	°C	

October 2003

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#### THERMAL DATA

R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	2	°C/W

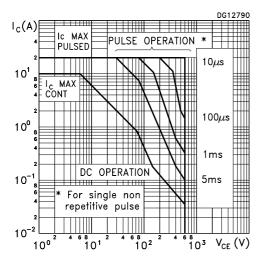
#### **ELECTRICAL CHARACTERISTICS** (T<sub>j</sub> = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector Cut-off Current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 1500 V V <sub>CE</sub> = 1500 V	T <sub>j</sub> = 125 °C			1 2	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current $(I_C = 0)$	V <sub>EB</sub> = 7 V				1	mA
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage $(I_B = 0)$	I <sub>C</sub> = 100 mA		600			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5 A	I <sub>B</sub> = 1.25 A			1.5	V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5 A	I <sub>B</sub> = 1.25 A			1.2	V
h <sub>FE</sub> *	DC Current Gain	$I_{C} = 6 A$ $I_{C} = 6 A$	V <sub>CE</sub> = 1 V V <sub>CE</sub> = 5 V	5	4.5	9	
t <sub>s</sub> t <sub>f</sub>	INDUCTIVE LOAD Storage Time Fall Time	$I_{C} = 5 \text{ A}$ $I_{Bon (END)} = 850 \text{ mA}$ $L_{BB(off)} = 2 \mu\text{H}$	$V_{BB(off)} = -2.5 V$ f <sub>h</sub> = 64 KHz (See Figure 1)		2.6 0.2	3 0.4	hs hs

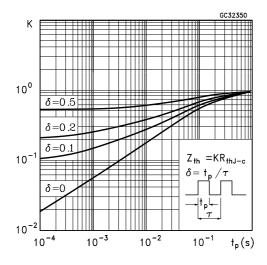
\* Pulsed: Pulse duration = 300 µs, duty cycle = 1.5 %.

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#### Safe Operating Area

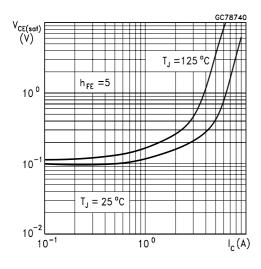


Thermal Impedance

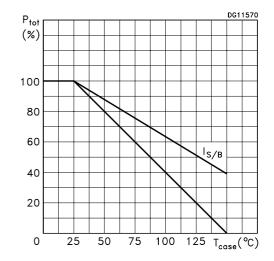


Collector-Emitter Saturation Voltage

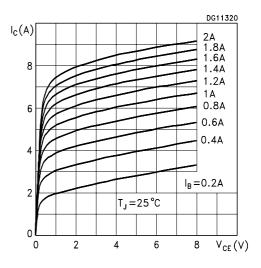
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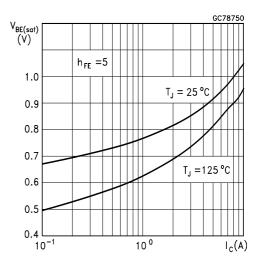
Derating Curve



#### **Output Characteristics**

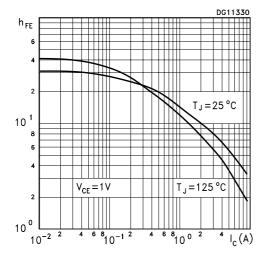


**Base-Emitter Saturation Voltage** 

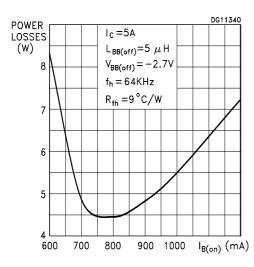


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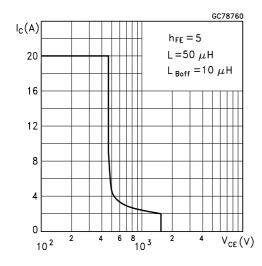
#### DC Current Gain



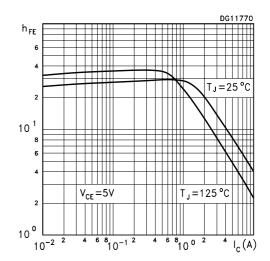
#### **Power Losses**

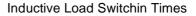


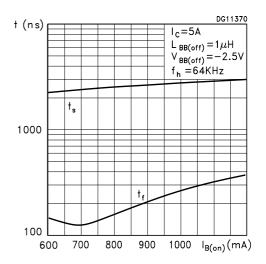
#### Reverse Biased Safe Operating Area



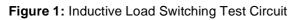
DC Current Gain

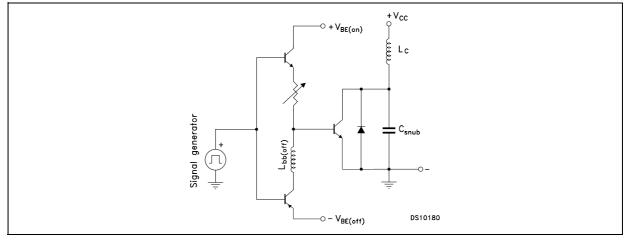






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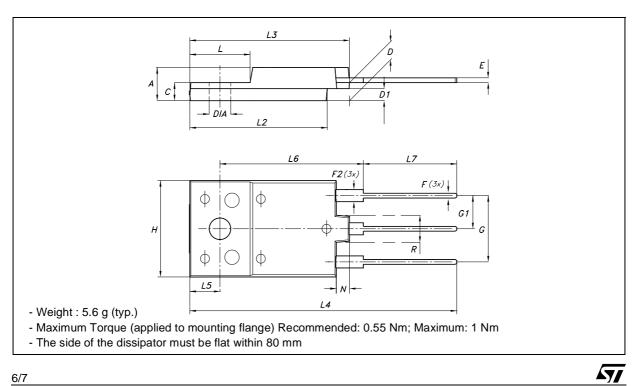




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# **ISOWATT218FX MECHANICAL DATA**

DIM		mm.			inch	
DIM.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	5.30		5.70	0.209		0.224
С	2.80		3.20	0.110		0.126
D	3.10		3.50	0.122		0.138
D1	1.80		2.20	0.071		0.087
Е	0.80		1.10	0.031		0.043
F	0.65		0.95	0.026		0.037
F2	1.80		2.20	0.071		0.087
G	10.30		11.50	0.406		0.453
G1		5.45			0.215	
Н	15.30		15.70	0.602		0.618
L	9.80		10.20	0.386		0.402
L2	22.80		23.20	0.898		0.913
L3	26.30		26.70	1.035		1.051
L4	43.20		44.40	1.701		1.748
L5	4.30		4.70	0.169		0.185
L6	24.30		24.70	0.957		0.972
L7	14.60		15.00	0.575		0.591
Ν	1.80		2.20	0.071		0.087
R	3.80		4.20	0.150		0.165
DIA	3.40		3.80	0.134		0.150



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